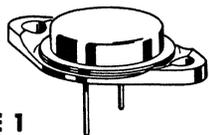


2N665 (GERMANIUM)



CASE 1
(TO-3)

PNP germanium power transistor for driver and power output amplifier and power switching applications in military and industrial equipment.

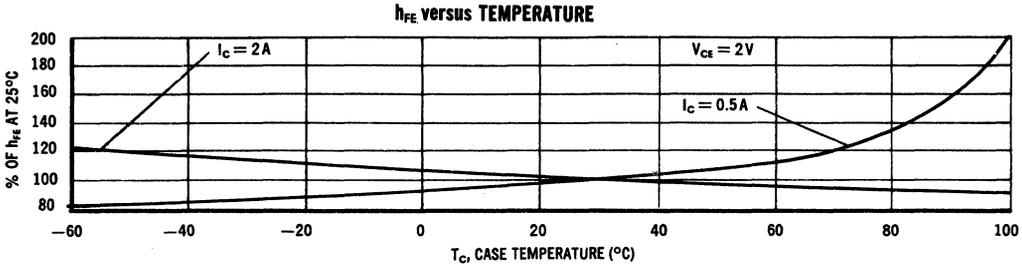
MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Base Voltage	V_{CB}	80	Vdc
Emitter-Base Voltage	V_{EB}	40	Vdc
DC Collector Current	I_C	3.0	Amp
DC Emitter Current	I_E	5.0	Amp
Collector Junction Temperature	T_J	-65 to +95	$^{\circ}C$
Collector Dissipation Derate above 25 $^{\circ}C$	P_D	35 0.5	Watts W/ $^{\circ}C$

ELECTRICAL CHARACTERISTICS

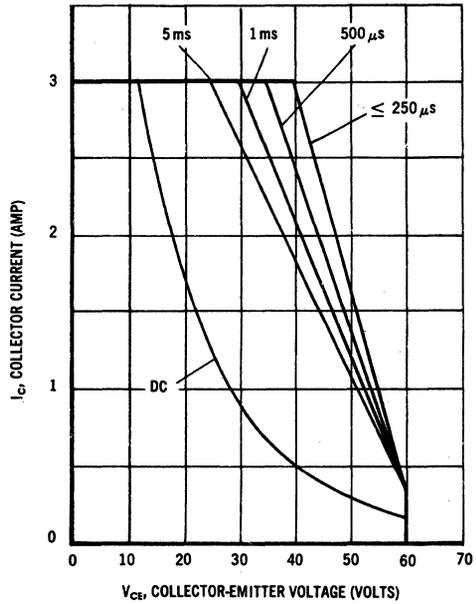
Characteristic	Symbol	Min	Max	Unit
Emitter Cutoff Current ($V_{EBO} = -40$ Vdc, $I_C = 0$)	I_{EBO}	—	2.0	mAdc
Collector Cutoff Current ($V_{CBO} = -2$ Vdc, $I_E = 0$) ($V_{CBO} = -60$ Vdc, $I_E = 0$) ($V_{CBO} = -80$ Vdc, $I_E = 0$)	I_{CBO}	— — —	0.05 2.0 10	mAdc
DC Current Gain ($V_{CE} = -2$ Vdc, $I_C = -0.5$ Adc) ($V_{CE} = -2$ Vdc, $I_C = -2$ Adc)	h_{FE}	40 20	80 —	—
Emitter-Base Voltage ($V_{CE} = -2$ Vdc, $I_C = -2$ Adc)	V_{EB}	—	1.5	Vdc
Floating Potential ($V_{CB} = -80$ Vdc, voltmeter input resistance = 10 megohms min, $t \approx 1$ sec)	V_{EBF}	—	1.0	Vdc
Collector-Emitter Saturation Voltage ($I_C = -3$ Adc, $I_B = -220$ mAdc)	$V_{CE(sat)}$	—	-0.9	Vdc
Collector-Emitter Voltage ($I_C = -300$ mAdc, $I_B = 0$)	V_{CEO}	40	—	Vdc
Small-Signal Short-Circuit Forward-Current Transfer-Ratio Cutoff Frequency ($V_{CE} = -14$ Vdc, $I_C = -2$ Adc)	$f_{\alpha e}$	20	—	kHz
Emitter Cutoff Current ($V_{EBO} = -30$ Vdc, $I_C = 0$, $T_C = +71^{\circ}C$ min)	I_{EBO}	—	2.0	mAdc
Collector Cutoff Current ($V_{CBO} = -30$ Vdc, $I_E = 0$, $T_C = +71^{\circ}C$ min)	I_{CBO}	—	2.0	mAdc

2N665 (continued)

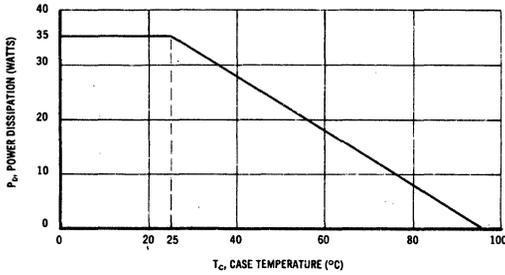


The Safe Operating Area Curves indicate $I_C - V_{CE}$ limits below which the device will not go into secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a collector-emitter short. (Duty cycle of the excursions make no significant change in these safe areas.) To insure operation below the maximum T_J , the power-temperature derating curve must be observed for both steady state and pulse power conditions.

SAFE OPERATING AREA



POWER-TEMPERATURE DERATING CURVE



2N669 (GERMANIUM)

For Specifications, See 2N176 Data.